

# PMCM6501UNE 20 V, N-channel Trench MOSFET 30 May 2017

Product data sheet

## 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a 6 bumps Wafer Level Chip-Size Package (WLCSP) using Trench MOSFET technology.

#### 2. Features and benefits

- Low threshold voltage
- Ultra small package: 0.98 × 1.48 × 0.35 mm
- Trench MOSFET technology •
- ElectroStatic Discharge (ESD) protection > 2 kV HBM •

#### 3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

#### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	20	V
V <sub>GS</sub>	gate-source voltage			-8	-	8	V
I <sub>D</sub>	drain current	$V_{GS}$ = 4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s	[1]	-	-	8.7	А
Static characteristics							
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = 4.5 V; I <sub>D</sub> = 3 A; T <sub>j</sub> = 25 °C		-	17	21	mΩ

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>

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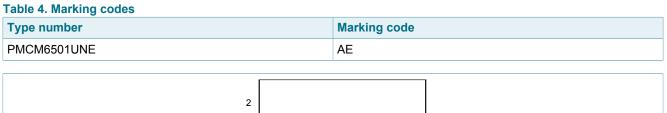
## 5. Pinning information

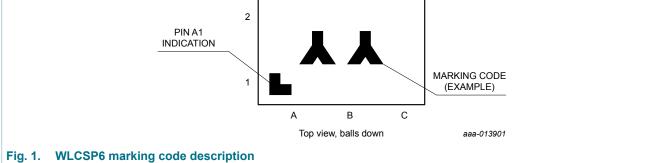
Table 2. F	Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
A1	G	gate	1 2	D
A2	S	source		
B1	S	source	в	G ← → ☆ ↓
B2	S	source		
C1	D	drain	c	
C2	D	drain	Transparent top view WLCSP6 (WLCSP6_3-2)	S 017aaa255

## 6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PMCM6501UNE	WLCSP6	wafer level chip-size package; 6 bumps (3 x 2)	WLCSP6_3-2			

## 7. Marking





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### 8. Limiting values

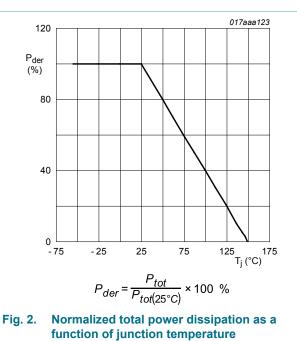
#### Table 5. Limiting values

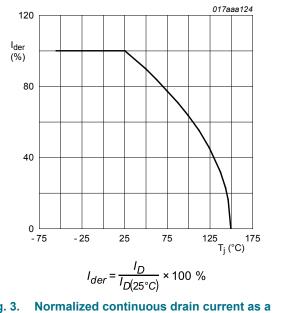
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	20	V
V <sub>GS</sub>	gate-source voltage			-8	8	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	8.7	А
		V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	6.6	А
		V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 100 °C	[1]	-	4.2	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	27	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	556	mW
			[1]	-	1.3	W
		T <sub>sp</sub> = 25 °C		-	12.5	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source Drai	n Diode		·			
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	1.2	А

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard footprint.

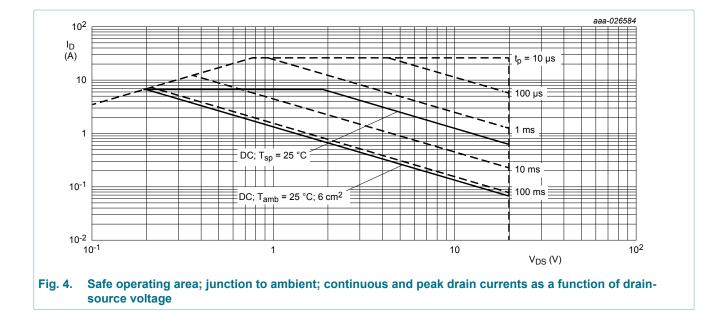






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## 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

	indi characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance	in free air	[1]	-	180	225	K/W
	from junction to ambient		[2]	-	65	85	K/W
			[3]	-	75	95	K/W
		t ≤ 5 s	[3]	-	45	55	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	5	10	K/W

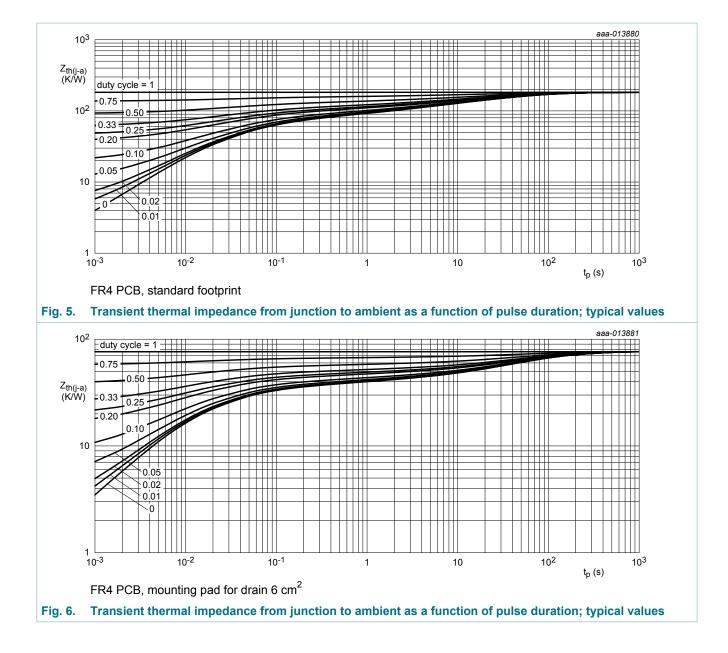
Device mounted on an FR4 Printed-Circuit Board (PCB), single sided-copper; tin-plated and standard footprint. Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain, 4 layer, 1 cm<sup>2</sup> [1]

[2]

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

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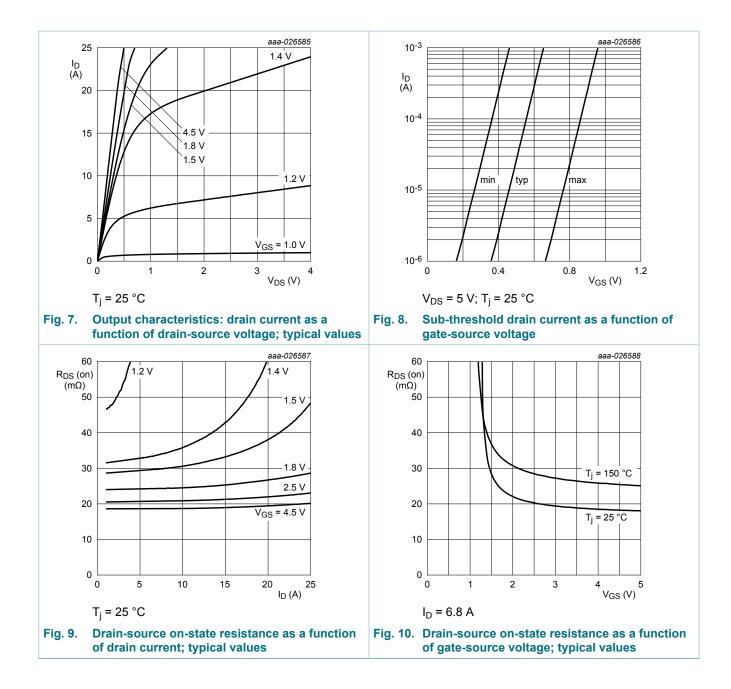
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## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		1		- 1	_,
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = 250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = 250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	0.4	0.6	0.9	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 20 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	1	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		$V_{GS}$ = -8 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-10	μA
		$V_{GS}$ = 4.5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	1	μA
		$V_{GS}$ = -4.5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
		$V_{GS}$ = 2.5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	200	nA
		$V_{GS}$ = -2.5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-200	nA
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 3 A; T <sub>j</sub> = 25 °C	-	17	21	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 3 A; T <sub>j</sub> = 150 °C	-	25	29	mΩ
		V <sub>GS</sub> = 2.5 V; I <sub>D</sub> = 3 A; T <sub>j</sub> = 25 °C	-	20	25	mΩ
		V <sub>GS</sub> = 1.8 V; I <sub>D</sub> = 2 A; T <sub>j</sub> = 25 °C	-	22	32	mΩ
		V <sub>GS</sub> = 1.5 V; I <sub>D</sub> = 1 A; T <sub>j</sub> = 25 °C	-	30	45	mΩ
9fs	forward transconductance	V <sub>DS</sub> = 5 V; I <sub>D</sub> = 3 A; T <sub>j</sub> = 25 °C	-	40	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz; T <sub>j</sub> = 25 °C	-	1.2	-	Ω
Dynamic ch	aracteristics					
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = 10 V; I <sub>D</sub> = 3 A; V <sub>GS</sub> = 4.5 V;	-	19	28	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	1.2	-	nC
Q <sub>GD</sub>	gate-drain charge		-	5.8	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS} = 10 \text{ V}; \text{ f} = 1 \text{ MHz}; \text{ V}_{GS} = 0 \text{ V};$	-	105	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	19	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	18	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 10 V; I <sub>D</sub> = 6.6 A; V <sub>GS</sub> = 4.5 V;	-	7.3	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	28	-	ns
t <sub>d(off)</sub>	turn-off delay time	1	-	100	-	ns
t <sub>f</sub>	fall time		-	46	-	ns
Source-drai	n diode					
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 1.2 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	0.6	1.2	V

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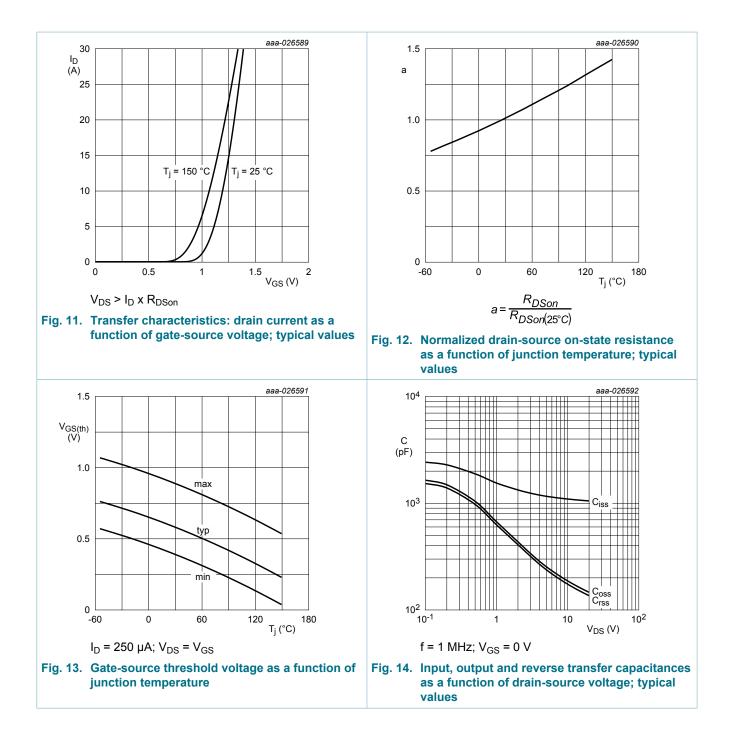
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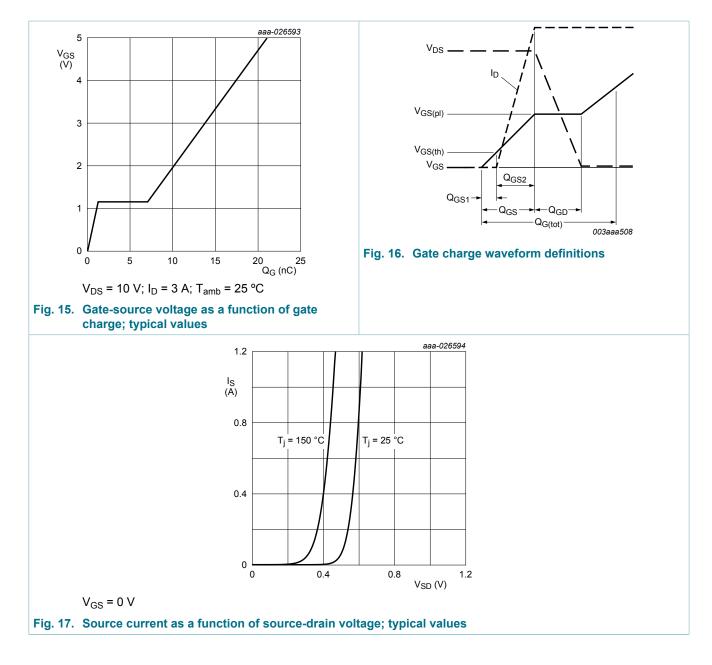
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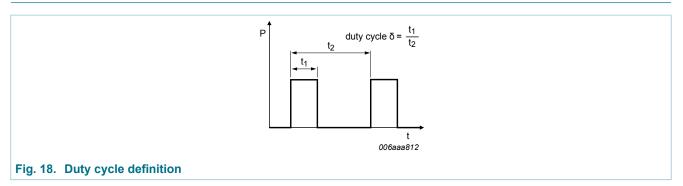


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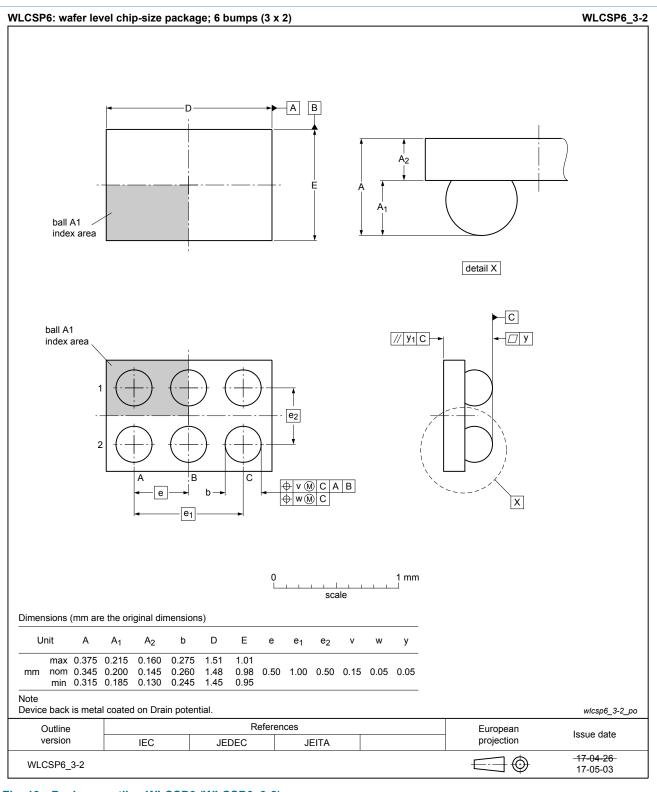


## **11. Test information**



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### 12. Package outline

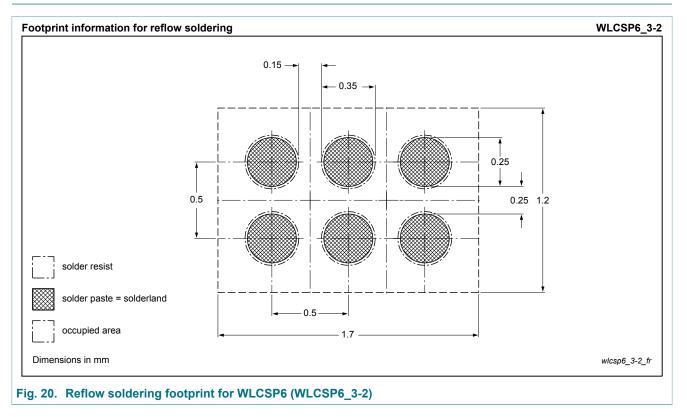


#### Fig. 19. Package outline WLCSP6 (WLCSP6\_3-2)

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## 13. Soldering



#### 20 V, N-channel Trench MOSFET

## 14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMCM6501UNE v.1	20170530	Product data sheet	-	-		

#### 20 V, N-channel Trench MOSFET

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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